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FAIRCHILD

74LCXH16245 Low Voltage 16-Bit Bidirectional Transceiver with Bushold

General Description

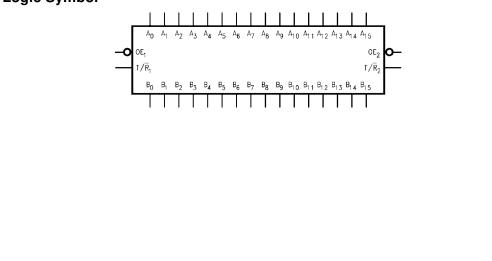
Features

- 2.3V–3.6V V_{CC} specifications provided
- = 4.5 ns t_{PD} max (V_{CC} = 3.3V), 20 μ A I_{CC} max
- Power-down high impedance outputs
- Bushold on inputs eliminates the need for external pull-up/pull-down resistors
- \blacksquare ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance conforms to the requirements of JESD78
- ESD performance: Human body model > 2000V
- Machine model > 200V
- Also packaged in plastic Fine-Pitch Ball Grid Array (FBGA)

Ordering Code:

74LCXH1 Low Volta with Bus	age 16-Bi	t Bidirection	al Transceiver			
tional buffers with 3 oriented application age (2.5V or 3.3V) facing to a 5V si controlled. Each b could be shorted to inputs determine 1 device. The \overline{OE} in placing them in a h The LCXH16245 of cuitry, eliminating t hold unused or floa The LCXH16245 i	contains sixteen no STATE outputs and ns. The device is device is device applications with gnal environment. yte has separate of gether for full 16-bit the direction of data bouts disable both th igh impedance state data inputs include he need for externa ting data inputs at a s fabricated with a eve high speed operation.	n-inverting bidirec- is intended for bus signed for low volt- h capability of inter- The device is byte ontrol inputs which operation. The T/R a flow through the e A and B Ports by active bushold cir- pull-up resistors to valid logic level. n advanced CMOS	Features 2.3V–3.6V V_{CC} specifications provided 4.5 ns t_{PD} max ($V_{CC} = 3.3V$), 20 μ A I_{CC} max Power-down high impedance outputs Bushold on inputs eliminates the need for external pull-up/pull-down resistors ± 24 mA output drive ($V_{CC} = 3.0V$) Implements patented noise/EMI reduction circuitry Latch-up performance conforms to the requirements of JESD78 ESD performance: Human body model > 2000V Machine model > 200V Also packaged in plastic Fine-Pitch Ball Grid Array (FBGA)			
Ordering C	ode:					
Order Number	Package Number		Package Description			
	BGA54A	54-Ball Fine-Pitch Ball G	all Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide			
74LCXH16245G (Note 1) (Note 2) 74LCXH16245MTD	MTD48		all Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide			

Logic Symbol



74LCXH16245

Connection Diagrams

Pin Assigni	nent for SSOP	and TSSOP
_		
τ/R ₁ —		48 — 0E ₁
в _о —		47 — A ₀
в ₁ — GND —		46 — A ₁ 45 — GND
в ₂ —		44 — A ₂
B ₃ —		43 — A ₃
v _{cc} –		42 V _{CC}
в ₄ —		41 — A ₄
в ₅ —	9	40 — A ₅
GND —	10	39 — GND
в ₆ —	11	38 — A ₆
в ₇ —	12	37 — A ₇
В ₈ —	13	36 — A ₈
в ₉ —	14	35 — A ₉
GND —	15	34 — GND
B ₁₀ —	16	33 — A ₁₀
B ₁₁ —		32 — A ₁₁
v _{cc} —		31 — V _{CC}
B ₁₂	19	30 — A ₁₂
B ₁₃ —	20	29 A ₁₃
GND —		28 — GND
^B 14 —	22	27 A ₁₄ 26 A ₁₅
B_{15} - T/ \overline{R}_2 -	24	$26 - A_{15}$ $25 - \overline{OE}_2$
17 12	24	20 012
Din A		
Pin A	ssignment for	
1	1 2 3 4 5	
< <	00000	
в С	00000	
0	00000	Šŏ I
ш	ŏŏŏŏŏ	5ŏ l
ш	00000	ō
ហ	00000	
т	00000	0
٦	00000	0
_	Top Thru View	<u>,</u>
		,

Pin Descriptions

Pin Names	Description
OEn	Output Enable Input
T/R _n	Transmit/Receive Input
A ₀ -A ₁₅	Side A Inputs or 3-STATE Outputs (Bushold)
B ₀ -B ₁₅	Side B Inputs or 3-STATE Outputs (Bushold)

FBGA Pin Assignments

	1	2	3	4	5	6
Α	B ₀	NC	T/R_1	OE ₁	NC	A ₀
В	B ₂	B ₁	NC	NC	A ₁	A ₂
С	B ₄	B ₃	V _{CC}	V _{CC}	A ₃	A ₄
D	B ₆	B ₅	GND	GND	A ₅	A ₆
E	B ₈	B ₇	GND	GND	A ₇	A ₈
F	B ₁₀	B ₉	GND	GND	A ₉	A ₁₀
G	B ₁₂	B ₁₁	V _{CC}	V _{CC}	A ₁₁	A ₁₂
Н	B ₁₄	B ₁₃	NC	NC	A ₁₃	A ₁₄
J	B ₁₅	NC	T/\overline{R}_2	OE ₂	NC	A ₁₅

Truth Tables

puts	Quitauta
T/R ₁	Outputs
L	Bus B_0-B_7 Data to Bus A_0-A_7
н	Bus A ₀ -A ₇ Data to Bus B ₀ -B ₇
Х	HIGH Z State on A_0-A_7 , B_0-B_7
outs	Outputs
T/R ₂	Outputs
L	Bus B ₈ –B ₁₅ Data to Bus A ₈ –A ₁₅
Н	Bus A ₈ -A ₁₅ Data to Bus B ₈ -B ₁₅
Х	HIGH Z State on A ₈ -A ₁₅ , B ₈ -B ₁₅
	L H X Duts T/R ₂ L H X Itage Level tage Level al edance

Symbol	Parameter	Value	Conditions	Units	
V _{CC}	Supply Voltage	-0.5 to +7.0		V	
V _I	DC Input Voltage	-0.5 to V _{CC} + 0.5		V	
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	v	
		–0.5 to V _{CC} + 0.5	Output in HIGH or LOW State (Note 4)	v	
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA	
ок	DC Output Diode Current	-50	V _O < GND		
		+50	$V_{O} > V_{CC}$	mA	
0	DC Output Source/Sink Current	±50		mA	
I _{CC}	DC Supply Current per Supply Pin	±100		mA	
I _{GND}	DC Ground Current per Ground Pin	±100		mA	
T _{STG}	Storage Temperature	-65 to +150		°C	

Recommended Operating Conditions (Note 5)

Symbol	Parameter	Parameter			
V _{CC}	Supply Voltage	2.0	3.6	v	
		Data Retention	1.5	3.6	v
VI	Input Voltage		0	V _{CC}	V
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	v
		3-STATE	0	V _{CC}	v
I _{OH} /I _{OL}	Output Current	V _{CC} = 3.0V – 3.6V		±24	
		$V_{CC}=2.7V-3.0V$		±12	mA
		$V_{CC} = 2.3V - 2.7V$		±8	
Τ _Α	Free-Air Operating Temperature		-40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V		0	10	ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 4: I_O Absolute Maximum Rating must be observed.

Note 5: Floating or unused control inputs must be HIGH or LOW.

DC Electrical Characteristics

Symbol	Parameter		Conditions	v _{cc}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
Symbol	Farameter		Conditions	(V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage			2.3 – 2.7	1.7		V
				2.7 – 3.6	2.0		v
VIL	LOW Level Input Voltage			2.3 – 2.7		0.7	V
				2.7 - 3.6		0.8	v
V _{OH}	HIGH Level Output Voltage		$I_{OH} = -100 \ \mu A$	2.3 – 3.6	V _{CC} - 0.2		
			I _{OH} = -8 mA	2.3	1.8		
			$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
			$I_{OH} = -18 \text{ mA}$	3.0	2.4		
			$I_{OH} = -24 \text{ mA}$	3.0	2.2		
V _{OL}	LOW Level Output Voltage		I _{OL} = 100 μA	2.3 - 3.6		0.2	
			I _{OL} = 8mA	2.3		0.6	
			I _{OL} = 12 mA	2.7		0.4	V
			I _{OL} = 16 mA	3.0		0.4	
			I _{OL} = 24 mA	3.0		0.55	
I _I	Input Leakage Current	Data	$V_I = V_{CC}$ or GND	2.3 - 3.6		±5.0	
		Control	$O \leq V_{I} \leq 5.5$	2.3 - 3.6		±5.0	μA

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DC Electrical Characteristics (Continued)

0	Parameter	Conditions	V _{cc}	$T_A = -40^{\circ}C$	C to +85°C	Units
Symbol	Falameter	Conditions	(V)	Min	Max	Units
I _{I(HOLD)}	Bushold Input Minimum	$V_{IN} = 0.7V$	2.3	45		
	Drive Hold Current	$V_{IN} = 1.7V$	2.5	-45		
		$V_{IN} = 0.8V$	3.0	75		μA
		$V_{IN} = 2.0V$	3.0	-75		
I _{I(OD)}	Bushold Input Over-Drive	(Note 6)	2.7	300		
	Current to Change State	(Note 7)	2.7	-300		μA
		(Note 6)	3.6	450		
		(Note 7)	5.0	-450		
I _{OZ}	3-STATE I/O Leakage	$V_O = V_{CC}$ or GND	2.3 - 3.6		±5.0	μA
I _{OFF}	Power-Off Leakage Current	$V_1 \text{ or } V_0 = 5.5 V$	0		10	μA
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–3.6		20	μA
Δl _{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3-3.6		500	μA

Note 7: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

AC Electrical Characteristics

		$T_A = -40^{\circ}C$ to $+85^{\circ}C$, $R_L = 500 \Omega$							
Symbol	Parameter	$V_{CC} = 3.3V \pm 0.3V$ $C_L = 50 \text{ pF}$		V _{CC} = 2.7V C _L = 50 pF		$V_{CC} = 2.5V \pm 0.2V$ $C_L = 30 \text{ pF}$		Units	
	Faranieter								
		Min	Max	Min	Max	Min	Max		
t _{PHL}	Propagation Delay	1.0	4.5	1.0	5.2	1.0	5.4		
t _{PLH}	A _n to B _n or B _n to A _n	1.0	4.5	1.0	5.2	1.0	5.4	ns	
t _{PZL}	Output Enable Time	1.0	6.5	1.0	7.2	1.0	8.5		
t _{PZH}		1.0	6.5	1.0	7.2	1.0	8.5	ns	
t _{PLZ}	Output Disable Time	1.0	6.4	1.0	6.9	1.0	7.7	ns	
t _{PHZ}		1.0	6.4	1.0	6.9	1.0	7.7		
t _{OSHL}	Output to Output Skew (Note 8)		1.0					ns	
tOSLH			1.0					115	

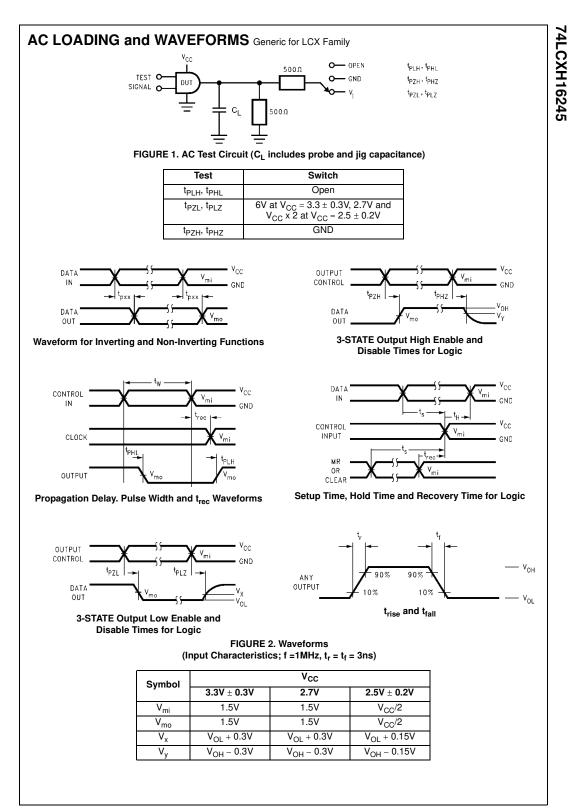
Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

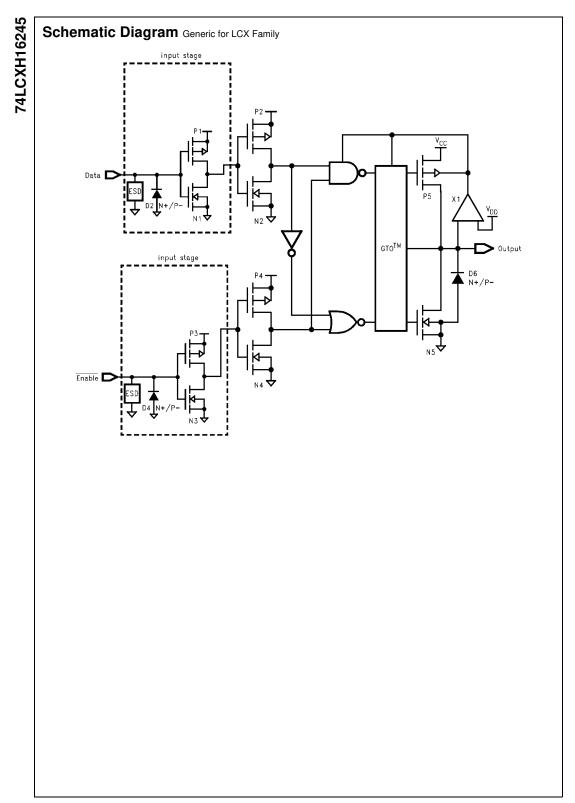
Symbol	Parameter	Conditions	V _{cc}	$T_A = 25^{\circ}C$	Units
Symbol	Faiantelei	Conditions	(V)	Typical	Units
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 50 \text{ pF}, \text{ V}_{IH} = 3.3 \text{V}, \text{ V}_{IL} = 0 \text{V}$	3.3	0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	0.6	v
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_{L} = 50 \text{ pF}, \text{ V}_{IH} = 3.3 \text{V}, \text{ V}_{IL} = 0 \text{V}$	3.3	-0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	-0.6	v

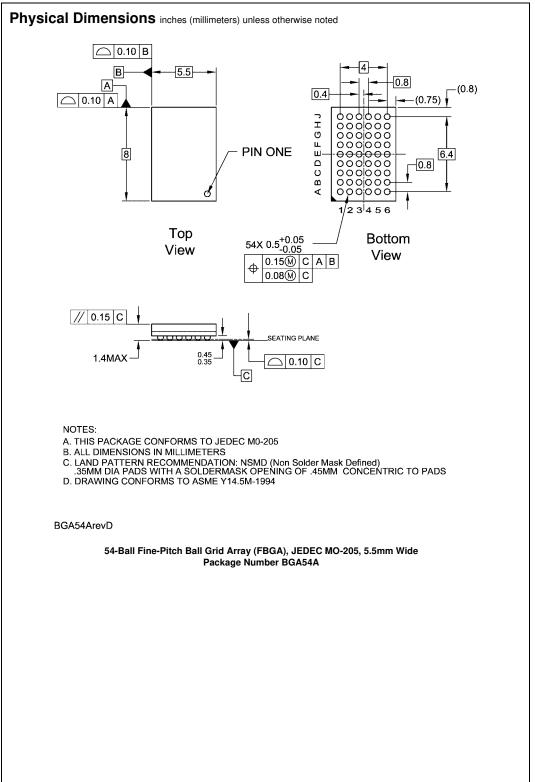
Capacitance

Symbol	Parameter	Conditions	Typical	Units
CIN	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{I/O}	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10 MHz	20	pF

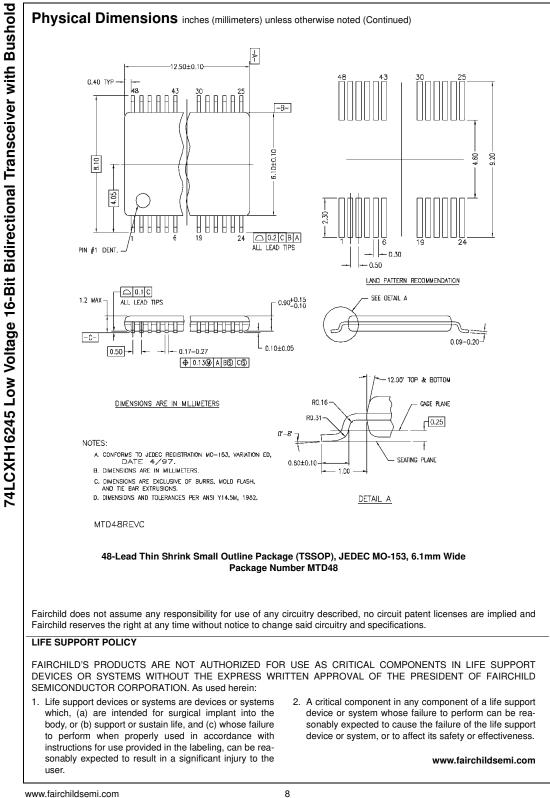


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